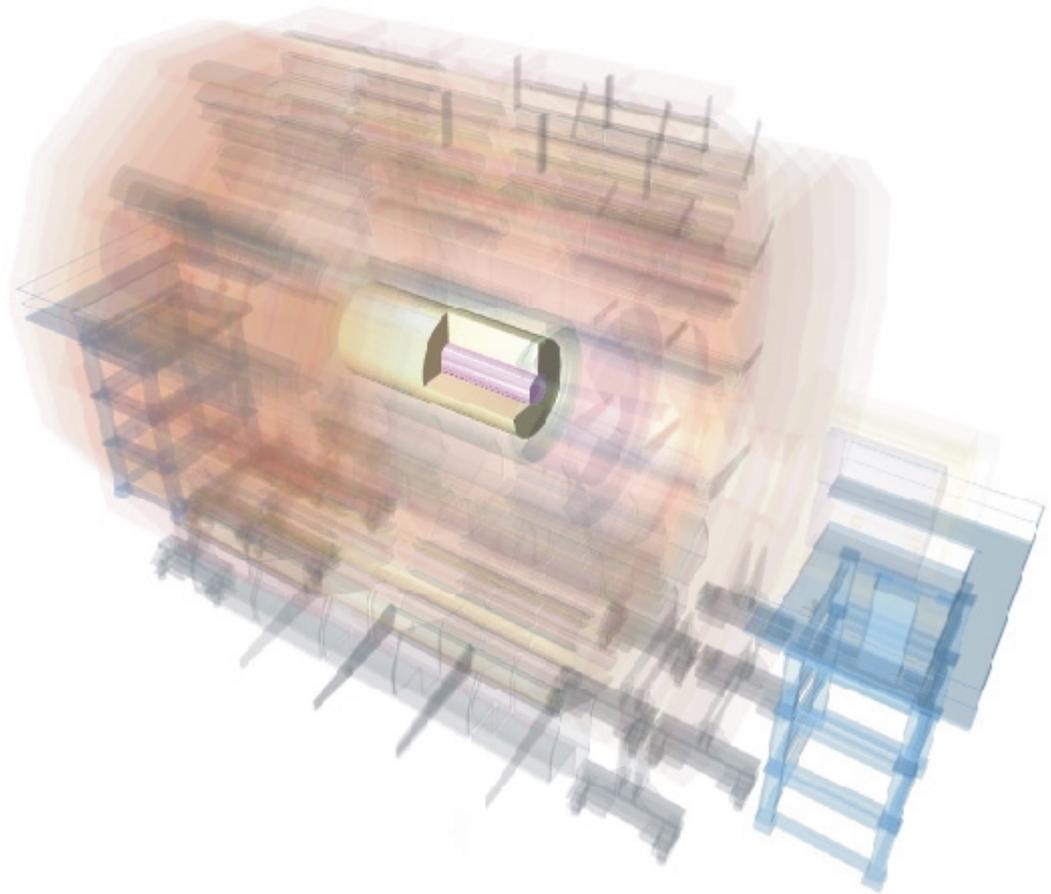


The CMS Silicon Strip Tracker and its Electronic Readout

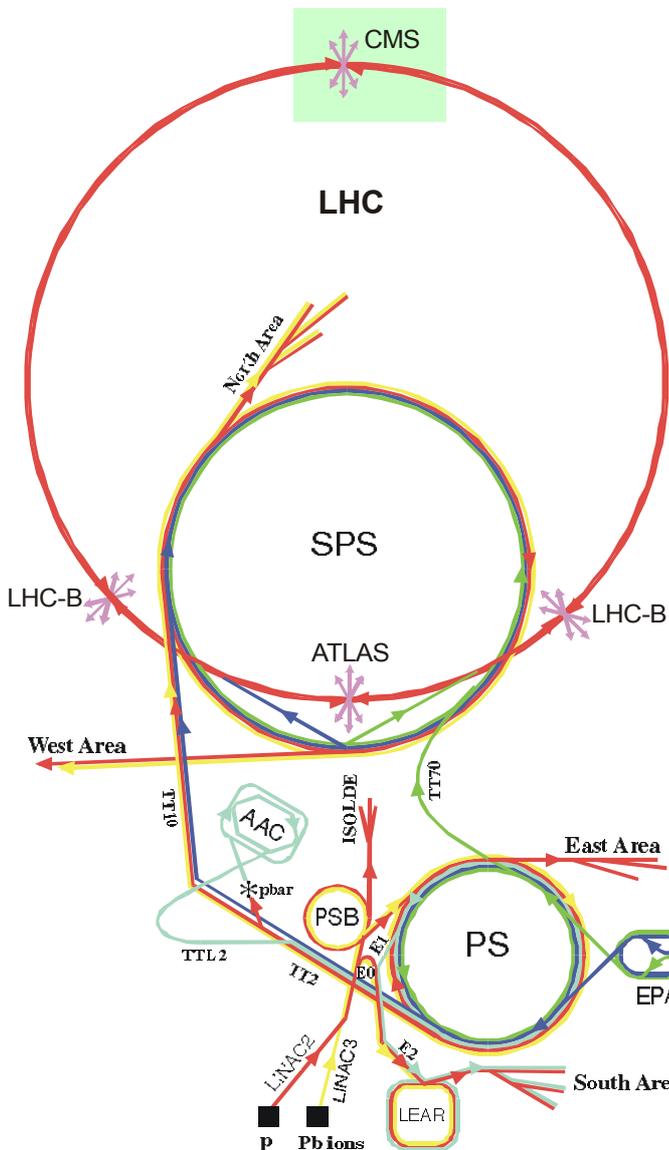


Markus Friedl · Dissertation · May 2001



Introduction

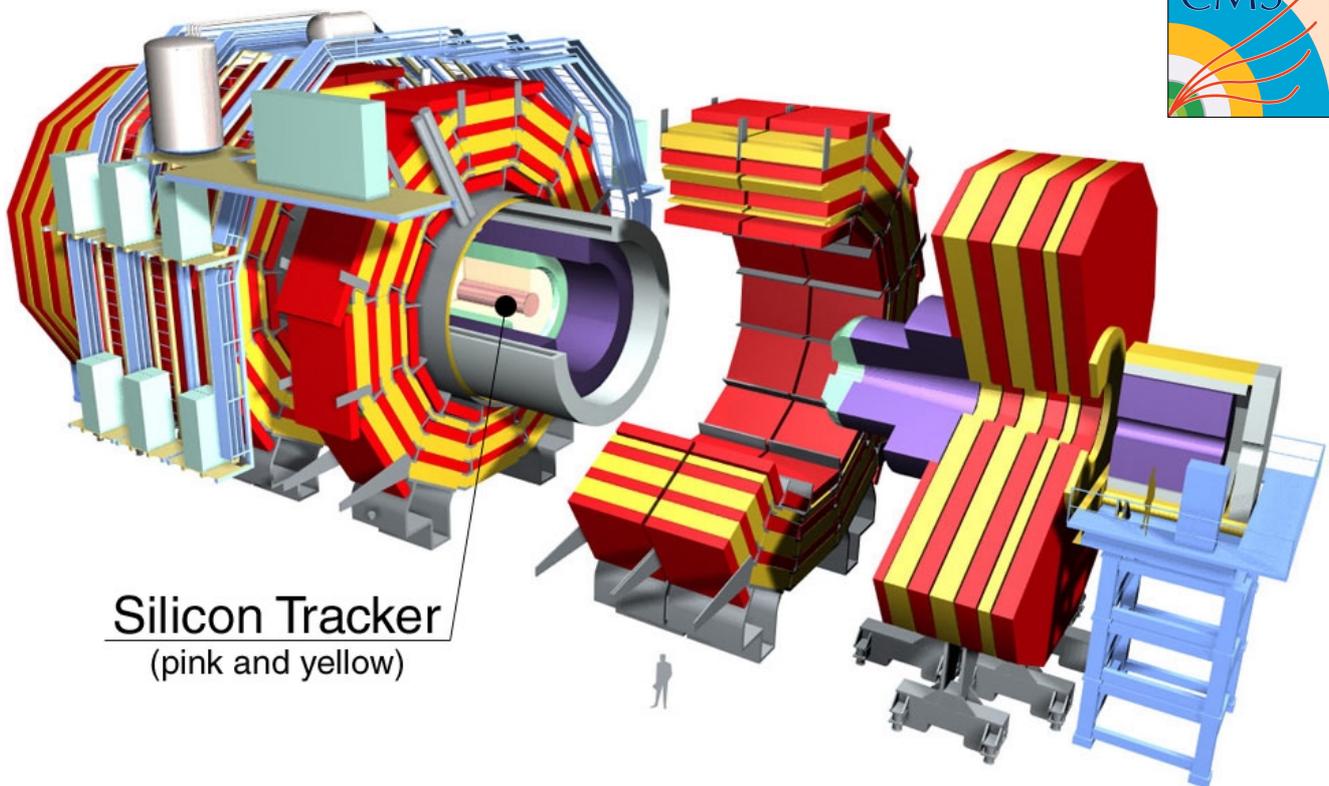
LHC Large Hadron Collider: future high energy physics accelerator at CERN (starts 2006)



Aim Measure new particles and their properties to verify the “Standard Model” (e.g. Higgs)

Introduction

CMS Compact Muon Solenoid: One of four collision detectors at LHC



Silicon Tracker
(pink and yellow)

Tracker Silicon strip and pixel detectors (206m²)
384 scientists from 42 institutes participate

Austria Insitute of High Energy Physics (HEPHY)
Austrian Academy of Sciences
Nikolsdorfergasse 18
A-1050 Vienna

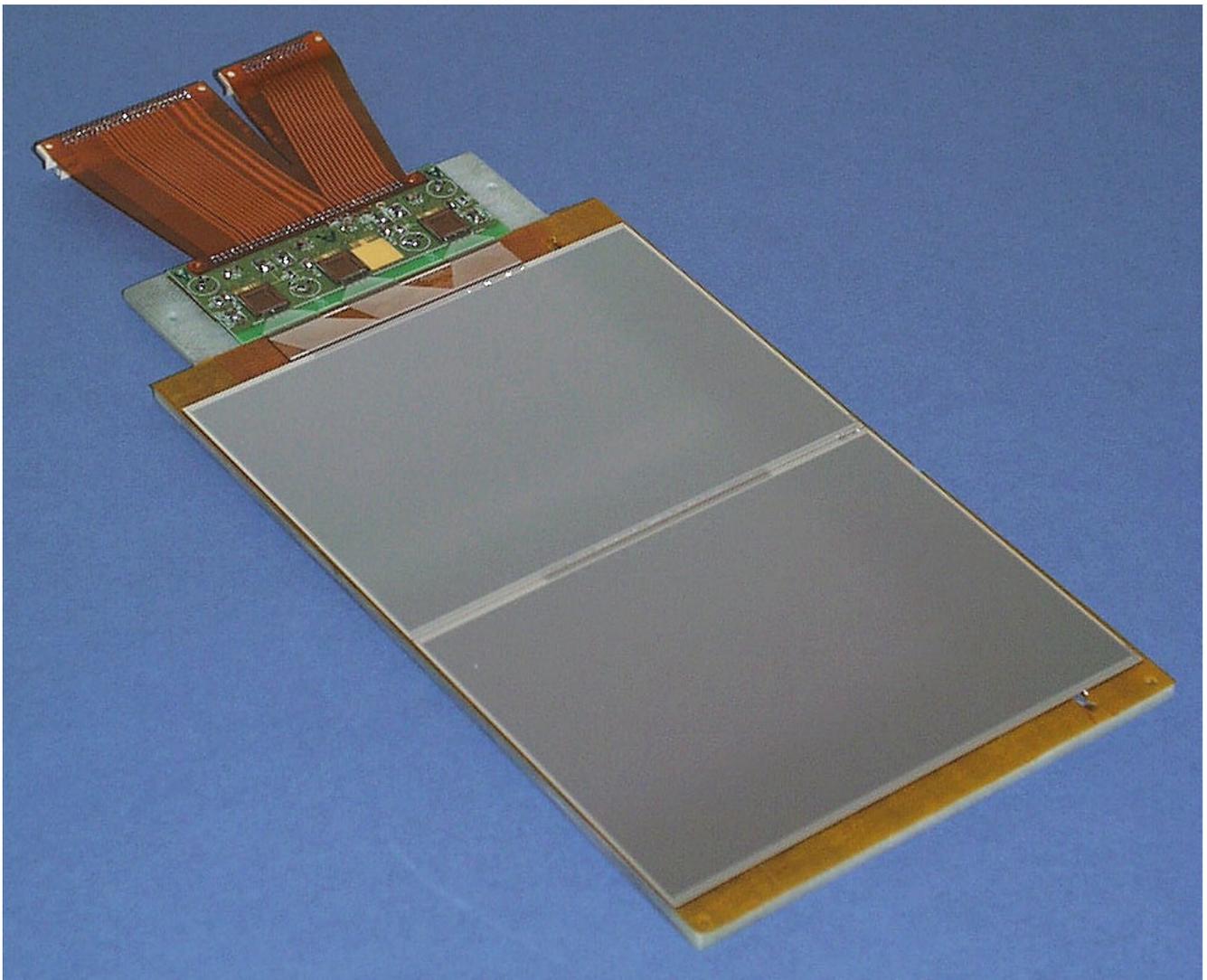
Thesis Contents

- LHC/CMS Introduction to future particle accelerator and collider experiment at CERN ✓
- Silicon detectors General principle and readout amplifiers including detector model and simulations (published in Nucl. Instr. Meth. A461 (2001) 192-196)
- CMS Silicon Tracker Details about configuration and readout electronics
- My research
 - Construction and tests of detector modules and readout components
 - Irradiation of detectors and electronics
 - Analog optical link evaluation
 - Magnetic field tests
 - ADC frequency response measurements

Silicon Detector Module Tests

CMS Silicon
Tracker

Prototype detector module with three APV25 front-end readout chips (HEPHY Vienna)



Tests

Characterized in particle beam together with other modules

System Overview

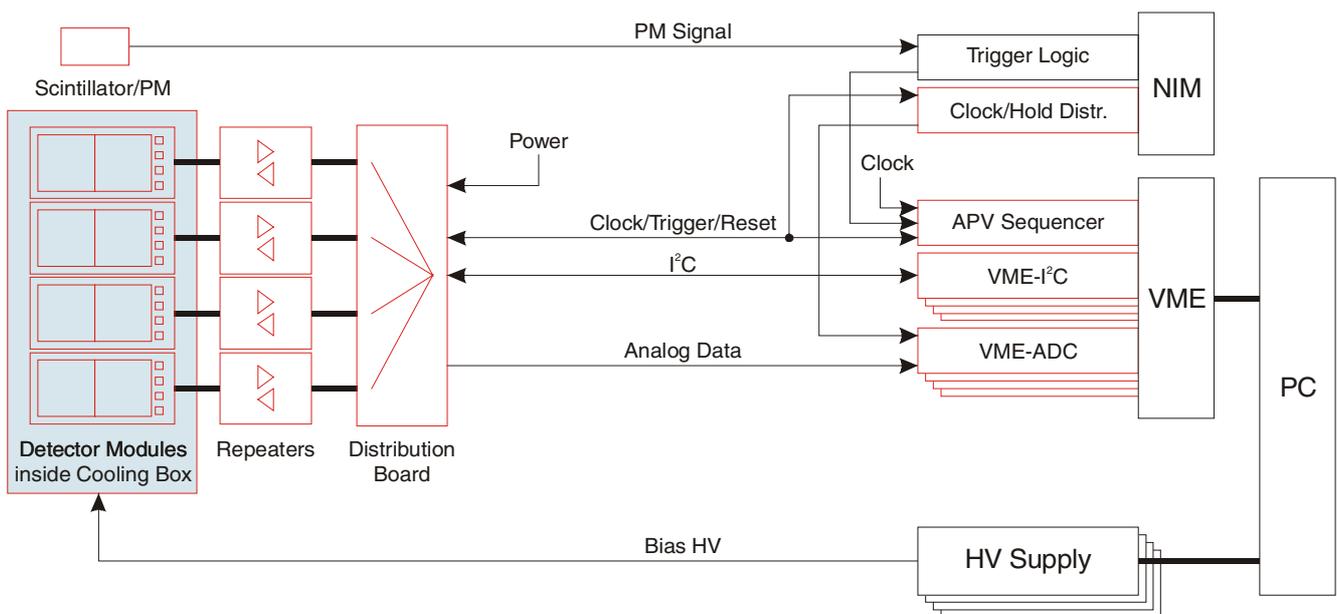
HEPHY
setup

Complete APV readout hardware

Cooling box for detector operation at -10°C

VME-based back-end system

PC-controlled data acquisition

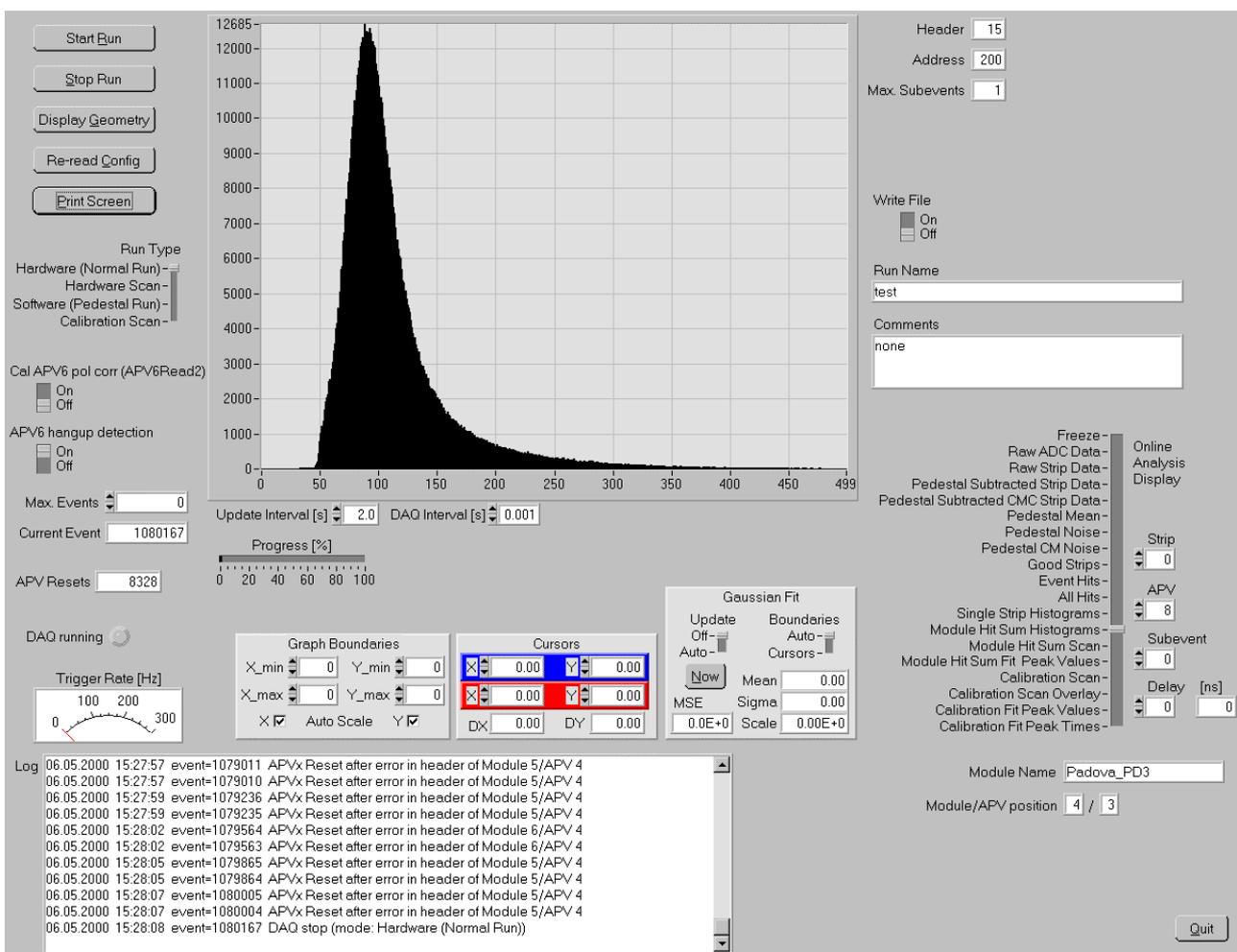


Components shown in red are self-made

System Overview

Software

Powerful control and readout system
(self-made)



Screenshot

Data acquisition software displaying
Landau signal distribution (online analysis)

Slow Control

Second PC for temperature and HV
control/monitoring

Pictures

Before installation at Paul Scherrer Institute (PSI) near Zurich



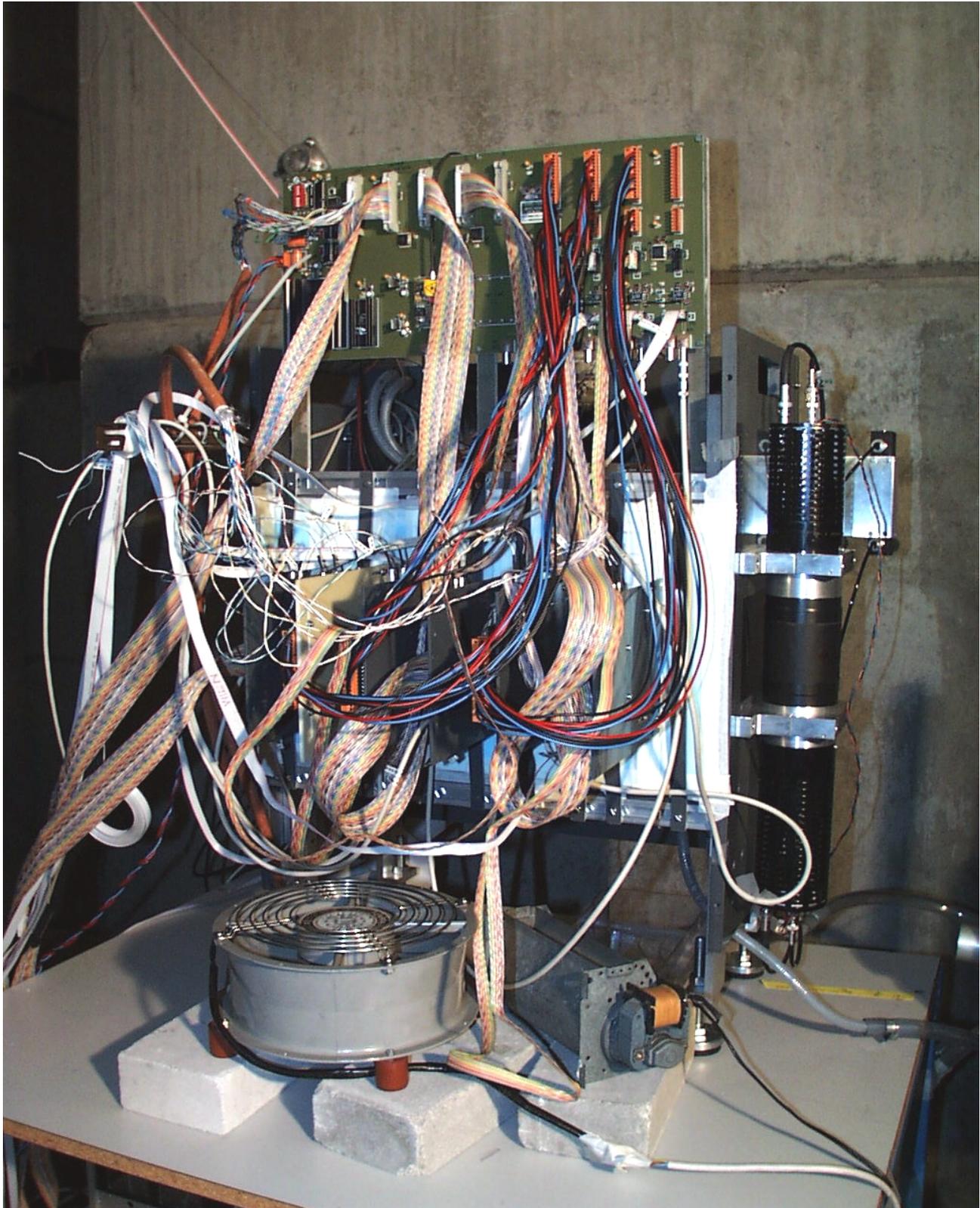


After installation in control room



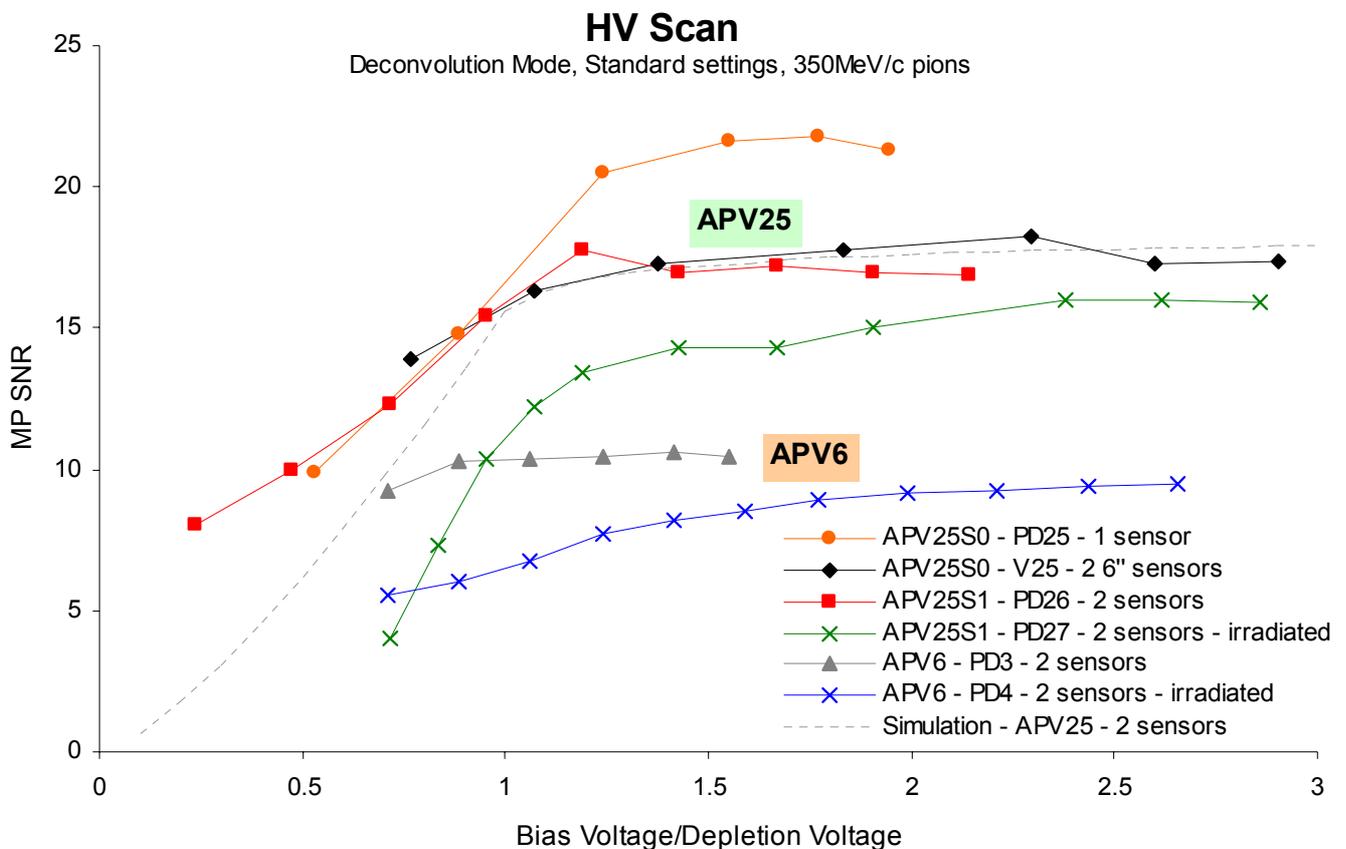


Fully equipped cooling box in beam area



Bias Voltage Scan

Selected data from beam tests



APV25

SNR \approx 17 for non-irradiated full-size module at CMS operating conditions

SNR > 10 is required for \approx 100% efficiency

\Rightarrow sufficient margin for irradiation degradation

APV25 outperforms previous APV6 version

High Intensity Beam

Silicon
detector

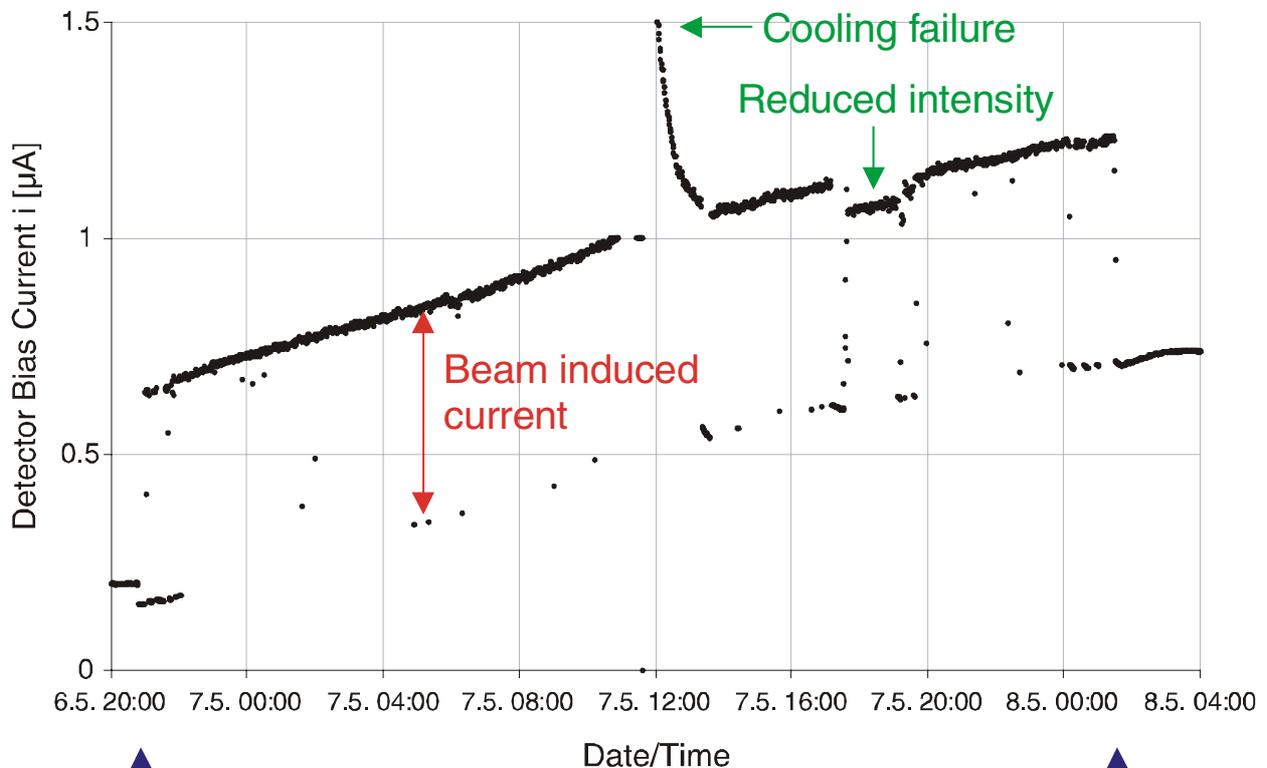
24 hours of LHC beam rate (1 MHz cm⁻² – corresponds to CMS r=12 cm)

Linear current increase, $\alpha \approx 8 \cdot 10^{-17} \text{ A cm}^{-1}$

Agrees with CERN RD48 (ROSE) collaboration measurements

Detector/APV25 performance unchanged

Vienna APV25 detector currents during high beam intensity

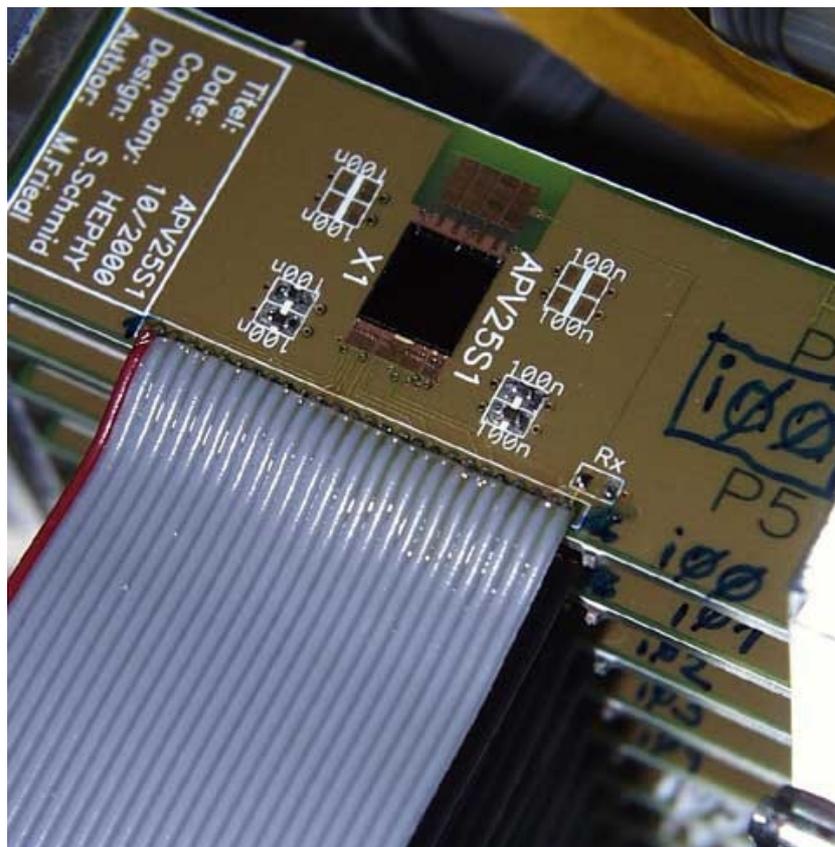


High intensity on

High intensity off

Electronics Irradiation

- Why? CMS front-end electronics must withstand hostile radiation environment
- Where? High intensity pion beam at Paul Scherrer Institute (PSI) near Zurich
- What? 8 APV25 CMS front-end readout chips produced in $0.25\mu\text{m}$ CMOS

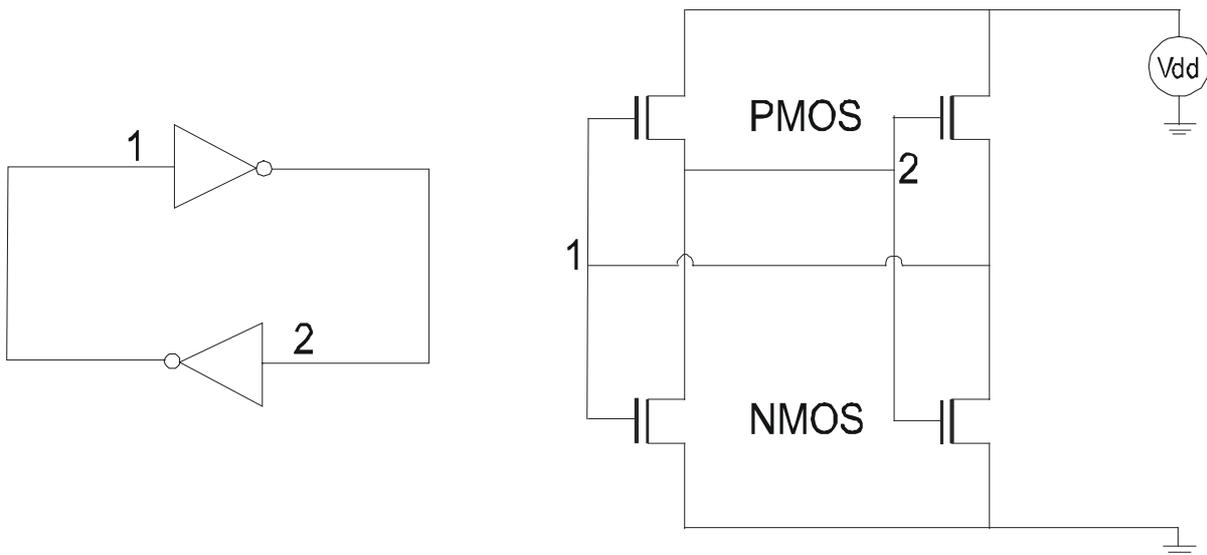


Radiation Effects

Effect	Scope	Damaging	Observed w/APV25
Single Event Upset (SEU)	digital	no	yes
	analog	no	yes
Single Event Latchup (SEL)	digital	yes	no

SEU Local charge deposition by highly ionizing particle (e.g. recoil atom)

SEU in digital logic Memory cell (flip-flop) changes state when enough charge is deposited on sensitive nodes (1 or 2)



State machine is disturbed until reset

Digital SEU Results

Cross
section

$$\sigma = \frac{N}{\Phi} \quad [cm^2]$$

Number of upsets divided by fluence

Measured: $\sigma = 2.25 \cdot 10^{-12} \text{ cm}^2$
(slightly depending on temperature)

Agrees with prediction from similar test with heavy ions

Extrapolation to CMS:

Section	Average Flux [cm ⁻² s ⁻¹]	Number of APVs	Mean SEU time [s]	SEUs/time [h ⁻¹]
Inner Barrel	1.40E+06	14400	22.1	162.7
Outer Barrel	4.85E+05	29232	31.4	114.7

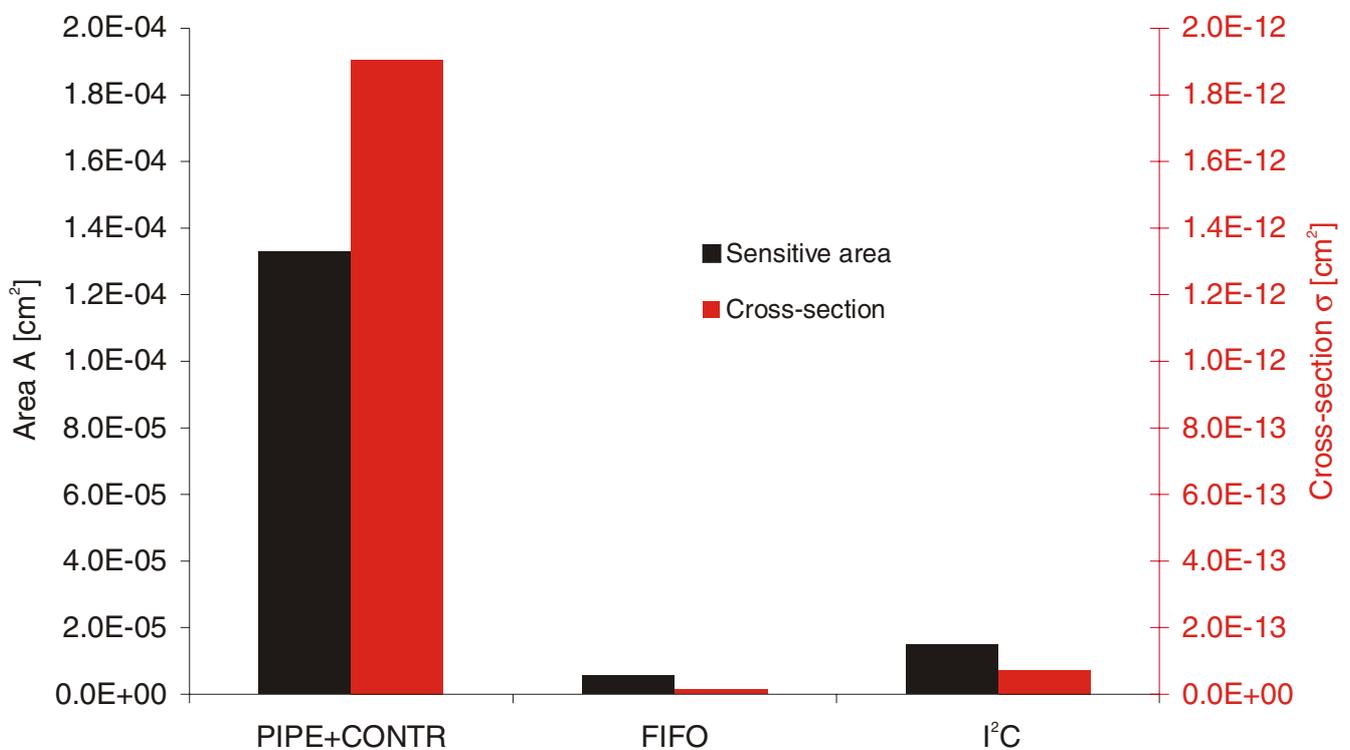
Periodic reset required to reactivate chips
which are stuck after SEU



Cross-Section and Sensitive Area

Comparison between chip areas and SEU cross-sections of different logic blocks

Sensitive area and cross-section



Principal agreement

Exact cross-section depends on electrical and geometrical circuit layout

Summary

CMS @ LHC

Future high energy detector experiment /
accelerator at CERN

Electronics

Full APV readout system developed at
HEPHY

Silicon
Detector

Important contributions to the CMS Silicon
Tracker R&D:

Prototype modules were assembled and
successfully tested in particle beams

Excellent SNR obtained

Radiation
effects

Detectors: Linear current increase observed

Electronics: Single Event Upset cross
section measured

Many more results within my thesis

Web

<http://cern.ch/friedl> → Dissertation